



NT600T12D3M7P

1200 V, 600 A Half Bridge IGBT Power Module

Rev. 1 — 25 June 2026

Product data sheet

1. General Description

The NT600T12D3M7P is an Insulated-Gate Bipolar Transistor (IGBT) power module that uses 7th-generation carrier stored trench-gate and field-stop (FS) technology. It is designed for high-voltage industrial power inverter and motor drive applications.

2. Features

- Half-bridge topology with NTC temperature sensor
- Rated voltage and current: 1200 V / 600 A
- Maximum junction temperature: 175 °C
- Short-circuit withstand time: 8 µs
- Solderable auxiliary contacts
- Optimized design for low parasitic inductance
- Low collector-emitter saturation voltage
- Low switching losses
- HV-H3TRB qualified
- Pre-applied thermal interface material

3. Applications

- Motor drives
- Renewable energy systems
- Electric vehicle (EV) chargers
- High power converters and inverters

4. Quick Reference Data

Table 1. Quick Reference Data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CES}	collector-emitter voltage	$T_{vj} = 25\text{ °C}$	-	-	1200	V
I_{CDC}	continuous DC collector current	$T_h = 45\text{ °C}$	-	-	722	A
		$T_h = 60\text{ °C}$	-	-	666	A
$T_{vj(op)}$	operating junction temperature		-40	-	175	°C

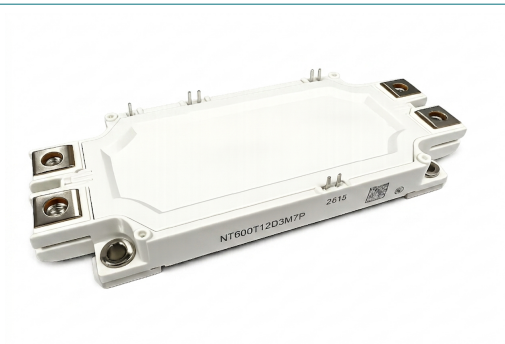


Fig. 1. Product Outline

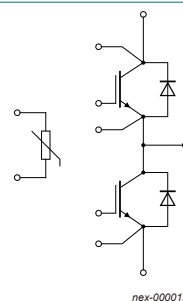


Fig. 2. Topology

5. Characteristic

5.1. IGBT

Table 2. Maximum Limiting Values

All values at $T_{vj} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CES}	collector-emitter voltage		-	1200	V
I_{CDC}	continuous DC collector current[1]	$T_h = 45\text{ }^{\circ}\text{C}$	-	722	A
		$T_h = 60\text{ }^{\circ}\text{C}$	-	666	A
I_{CRM}	repetitive peak collector current[2]		-	1200	A
V_{GE}	gate-emitter voltage		-20	20	V
$T_{vj(op)}$	operating junction temperature		-40	175	$^{\circ}\text{C}$
t_{sc}	short-circuit withstand time[3]	$V_{GE} = \pm 15\text{ V}$; $V_{CC} = 800\text{ V}$; $T_{vj} \leq 150\text{ }^{\circ}\text{C}$	-	8	μs

- [1] Value is give at chip level, and is limited by $T_{vj(max)}$.
[2] Time duration is limited by $T_{vj(max)}$.
[3] Short-circuit cycles ≤ 1000 . Time between tests $\geq 10\text{ s}$.

Table 3. Electrical Characteristics

All values at $T_{vj} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
$V_{CE(sat)}$	collector-emitter saturation voltage[1]	$V_{GE} = 15\text{ V}$; $I_C = 600\text{ A}$	-	1.52	1.79	V
		$V_{GE} = 15\text{ V}$; $I_C = 600\text{ A}$; $T_{vj} = 125\text{ }^{\circ}\text{C}$	-	1.69	-	V
		$V_{GE} = 15\text{ V}$; $I_C = 600\text{ A}$; $T_{vj} = 175\text{ }^{\circ}\text{C}$	-	1.77	-	V
$V_{GE(th)}$	gate-emitter threshold voltage	$I_C = 12\text{ mA}$; $V_{CE} = V_{GE}$	5.15	5.75	6.45	V
I_{CES}	zero gate voltage collector current	$V_{CE} = 1200\text{ V}$; $V_{GE} = 0\text{ V}$	-	-	100	μA
I_{GES}	gate-emitter leakage current	$V_{CE} = 0\text{ V}$; $V_{GE} = 20\text{ V}$	-	-	100	nA
r_g	internal gate resistor	$f = 100\text{ kHz}$	-	0.7	-	Ω
C_{ies}	input capacitance	$V_{CE} = 25\text{ V}$; $V_{GE} = 0\text{ V}$; $f = 100\text{ kHz}$	-	124	-	nF
C_{oes}	output capacitance		-	2.0	-	nF
C_{res}	reverse transfer capacitance		-	0.40	-	nF
Q_G	gate charge	$V_{CC} = 600\text{ V}$; $I_C = 600\text{ A}$; $V_{GE} = \pm 15\text{ V}$	-	9.5	-	μC

- [1] Value is given at chip level.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit		
Switching Characteristics								
t _{d(on)}	turn-on delay time	V _{GE} = ± 15 V; V _{CC} = 600 V; I _C = 600 A; R _{G(on)} = 0.51 Ω; R _{G(off)} = 0.51 Ω di/dt = 7500 A/μs (only at turn-on, T _{vj} = 175 °C) dv/dt = 3600 V/μs (only at turn-off, T _{vj} = 175 °C)	T _{vj} = 25 °C	-	361	-	ns	
			T _{vj} = 125 °C	-	381	-	ns	
			T _{vj} = 175 °C	-	395	-	ns	
t _r	rise time		T _{vj} = 25 °C	-	57	-	ns	
			T _{vj} = 125 °C	-	60	-	ns	
			T _{vj} = 175 °C	-	66	-	ns	
t _{d(off)}	turn-off delay time		T _{vj} = 25 °C	-	366	-	ns	
			T _{vj} = 125 °C	-	447	-	ns	
			T _{vj} = 175 °C	-	478	-	ns	
t _f	fall time		T _{vj} = 25 °C	-	152	-	ns	
			T _{vj} = 125 °C	-	287	-	ns	
			T _{vj} = 175 °C	-	374	-	ns	
E _{on}	turn-on switching energy loss		T _{vj} = 25 °C	-	29	-	mJ	
			T _{vj} = 125 °C	-	42	-	mJ	
			T _{vj} = 175 °C	-	51	-	mJ	
E _{off}	turn-off switching energy loss		T _{vj} = 25 °C	-	54	-	mJ	
			T _{vj} = 125 °C	-	78	-	mJ	
			T _{vj} = 175 °C	-	91	-	mJ	
I _{C(sc)}	short-circuit data		V _{GE} = ±15 V; V _{CC} = 800 V; V _{CEmax} = V _{CES} - L _{sCE} * di/dt	t _p ≤ 8 μs; T _{vj} = 150 °C	-	2187	-	A
				t _p ≤ 6 μs; T _{vj} = 175 °C	-	2080	-	A
Thermal Resistance								
R _{th(j-h)}	thermal resistance from junction to heatsink	per IGBT switch with pre-applied thermal interface material	-	-	0.0793	K/W		

5.2. Diode

Table 4. Maximum Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage	T _{vj} = 25 °C	-	1200	V
I _F	continuous DC forward current[1]		-	600	A
I _{FRM}	repetitive peak forward current[2]		-	1200	A
I ² t	I ² t value	V _R = 0 V; t _p = 10 ms; T _{vj} = 175 °C	-	27500	A ² s
T _{vj(op)}	operating junction temperature		-40	175	°C

[1] Value is given at chip level, and is limited by T_{vj(max)}.
[2] Time duration is limited by T_{vj(max)}.

Table 5. Electrical Characteristics

All values at $T_{vj} = 25\text{ °C}$, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V _F	diode forward voltage[1]	V _{GE} = 0 V; I _F = 600 A	T _{vj} = 25 °C	-	1.79	2.11	V
			T _{vj} = 125 °C	-	1.66	-	V
			T _{vj} = 175 °C	-	1.59	-	V
t _{rr}	reverse recovery time	V _R = 600 V; I _F = 600 A; V _{GE} = 0 V di _F /dt = 8200 A/μs (only at T _{vj} = 175 °C)	T _{vj} = 25 °C	-	280	-	ns
			T _{vj} = 125 °C	-	382	-	ns
			T _{vj} = 175 °C	-	473	-	ns
Q _{rr}	reverse recovery charge		T _{vj} = 25 °C	-	37	-	nC
			T _{vj} = 125 °C	-	72	-	nC
			T _{vj} = 175 °C	-	104	-	nC
I _{rrm}	peak reverse recovery current		T _{vj} = 25 °C	-	290	-	A
			T _{vj} = 125 °C	-	411	-	A
			T _{vj} = 175 °C	-	478	-	A
E _{rec}	reverse recovery energy loss		T _{vj} = 25 °C	-	17	-	mJ
			T _{vj} = 125 °C	-	33	-	mJ
			T _{vj} = 175 °C	-	47	-	mJ
R _{th(j-h)}	thermal resistance from junction to heatsink	per diode switch with pre-applied thermal interface material		-	-	0.1233	K/W

[1] Value is given at chip level.

5.3. NTC Thermistor

Table 6. NTC Thermistor

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R_{25}	rated resistance	$T_{NTC} = 25\text{ °C}$	-	5	-	kΩ
$\Delta R/R$	deviation of R_{100}	$T_{NTC} = 100\text{ °C}; R_{100} = 491$	-5.5	-	5.5	%
P_{25}	power dissipation	$T_{NTC} = 25\text{ °C}$	-	-	20	mW
$B_{25/50}$	B-value		-	3375	-	K
$B_{25/80}$	B-value		-	3425	-	K
$B_{25/100}$	B-value		-	3443	-	K

5.4. Package

Table 7. Mechanical Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
RTI	relative thermal index	housing only	-	140	-	°C
L _{sCE}	internal stray inductance		-	20	-	nH
R _{CC'+EE'}	lead resistance, terminal to chip	T _c = 25 °C, per switch	-	0.6	-	mΩ
M	mounting torque for heatsink	M5 screw	3	-	6	Nm
	mounting torque for terminal	M6 screw	3	-	6	Nm
G	weight		-	357	-	g
T _{stg}	storage temperature ^[1]		-40	-	125	°C
T _{BP(max)}	maximum baseplate operation temperature		-	-	150	°C

[1] Use the application note for special storage instructions when the product has pre-applied thermal interface material.

Table 8. Insulation

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{ISOL}	isolation test voltage	RMS; f = 50 Hz; t = 1 min	-	3.4	-	kV
	material of baseplate		-	Cu	-	-
	material of substrate isolation		-	Al ₂ O ₃	-	-
	creepage distance	terminal to baseplate	-	15.0	-	mm
		terminal to terminal	-	19.3	-	mm
	clearance distance	terminal to baseplate	-	12.5	-	mm
		terminal to terminal	-	10.0	-	mm
CTI	comparative tracking index		200	-	-	-

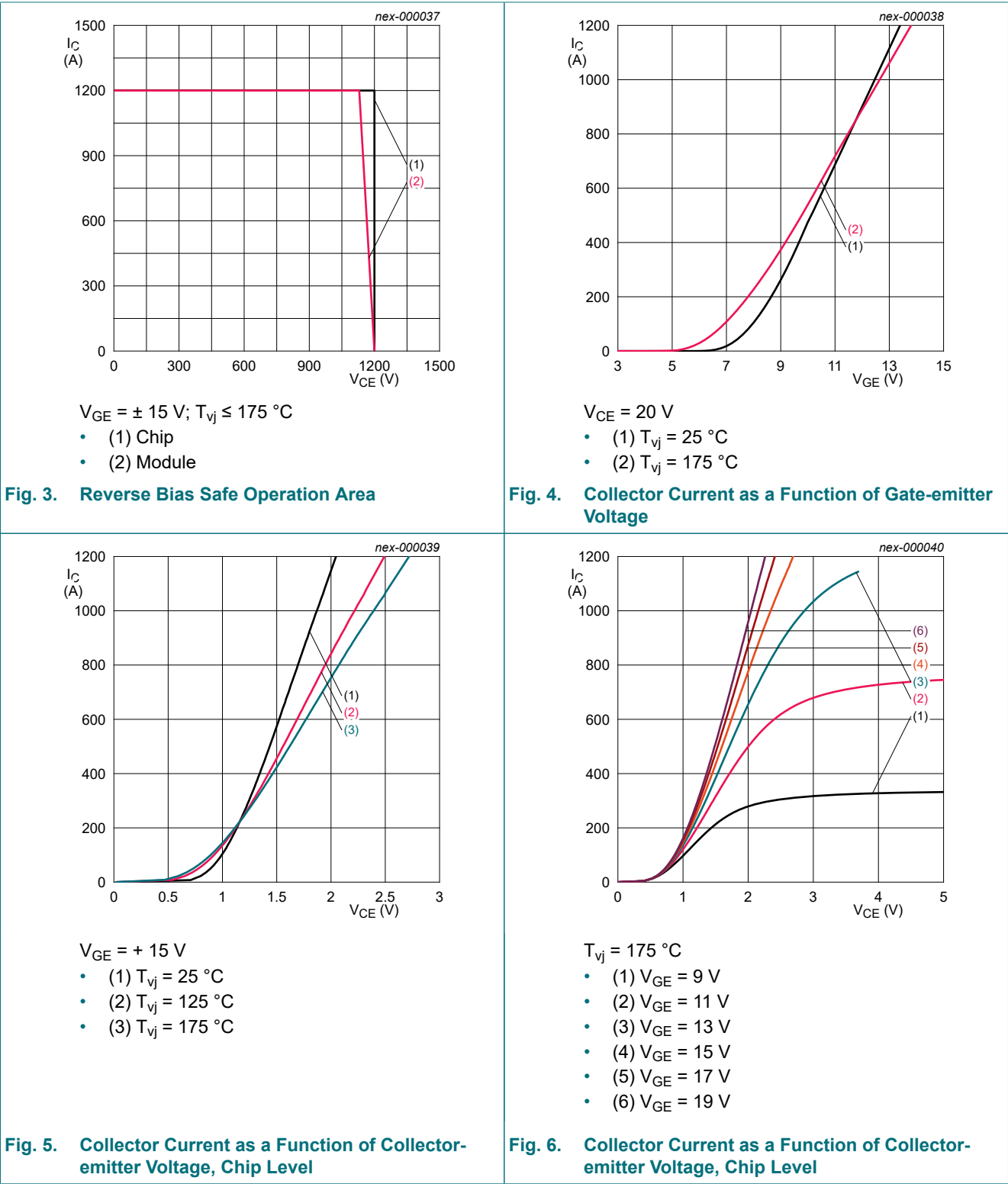
6. Ordering Information

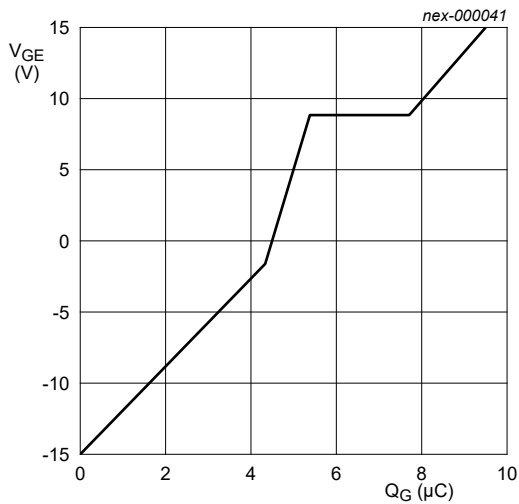
Table 9. Ordering information

Type number	Package		
	Name	Description	Version
NT600T12D3M7P	ND3	IGBT power module with half-bridge circuit topology; Solderable auxiliary contacts; Pre-applied thermal interface material; Outline dimension 152 mm × 62.5 mm × 20.8 mm	SOT8066-1

7. Characteristic Diagram

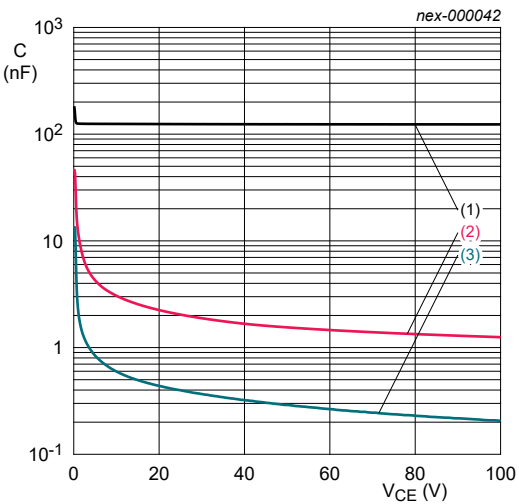
Table 10. Waveforms and Output Characteristics





$I_C = 600 \text{ A}$; $V_{CE} = 600 \text{ V}$

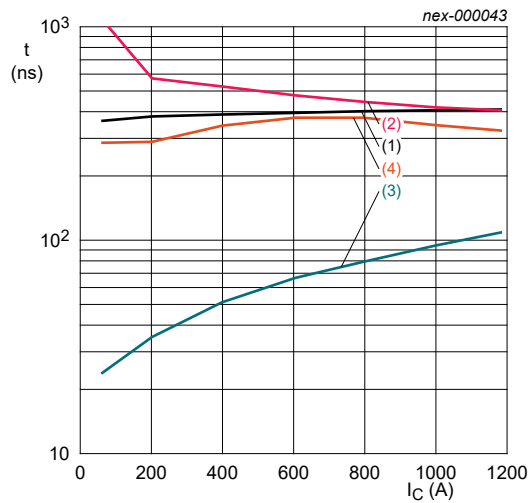
Fig. 7. Gate-emitter Voltage as a Function of Gate Charge



$V_{GE} = 0 \text{ V}$; $f = 100 \text{ kHz}$

- (1) C_{ies}
- (2) C_{oes}
- (3) C_{res}

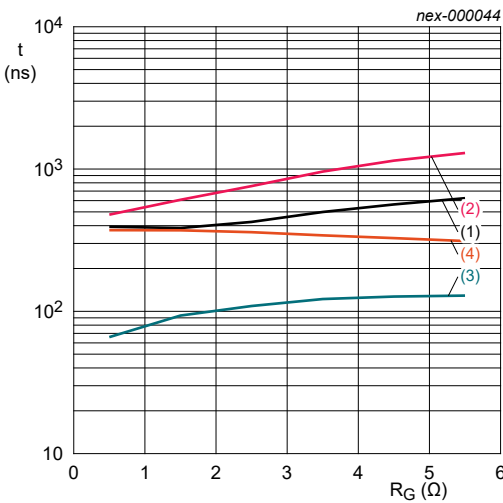
Fig. 8. Typical Capacitance as a Function of Collector-emitter Voltage



$V_{GE} = \pm 15 \text{ V}$; $V_{CC} = 600 \text{ V}$; $T_{vj} = 175 \text{ }^\circ\text{C}$;
 $R_{G(on)} = R_{G(off)} = 0.51 \text{ } \Omega$

- (1) $t_{d(on)}$
- (2) $t_{d(off)}$
- (3) t_r
- (4) t_f

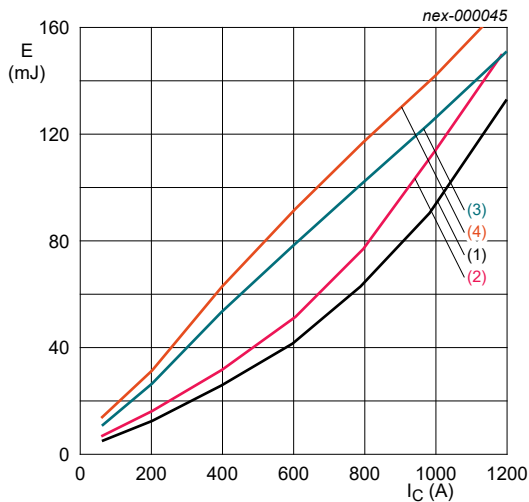
Fig. 9. Typical Switching Times as a Function of Collector Current



$V_{GE} = \pm 15 \text{ V}$; $V_{CC} = 600 \text{ V}$; $I_C = 600 \text{ A}$; $T_{vj} = 175 \text{ }^\circ\text{C}$

- (1) $t_{d(on)}$
- (2) $t_{d(off)}$
- (3) t_r
- (4) t_f

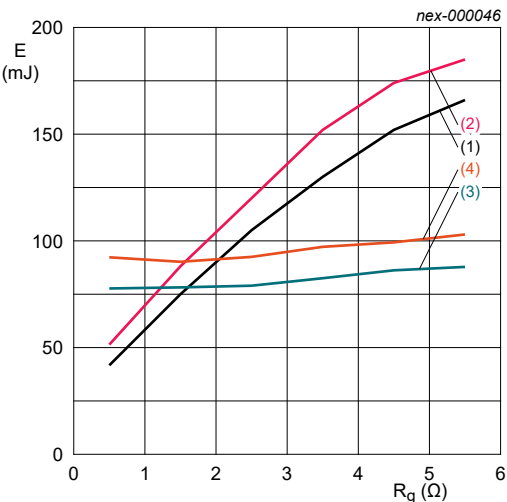
Fig. 10. Typical Switching Times as a Function of Gate Resistance



$V_{GE} = \pm 15 \text{ V}$; $V_{CC} = 600 \text{ V}$; $R_{G(on)} = R_{G(off)} = 0.51 \text{ }\Omega$

- (1) E_{on} , $T_{vj} = 125 \text{ }^{\circ}\text{C}$
- (2) E_{on} , $T_{vj} = 175 \text{ }^{\circ}\text{C}$
- (3) E_{off} , $T_{vj} = 125 \text{ }^{\circ}\text{C}$
- (4) E_{off} , $T_{vj} = 175 \text{ }^{\circ}\text{C}$

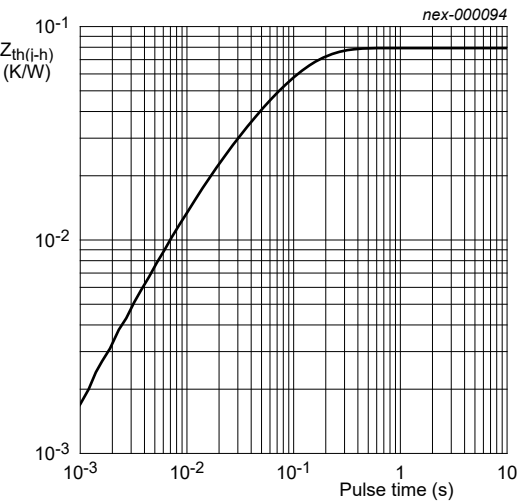
Fig. 11. Typical Switching Energy Losses as a Function of Collector Current



$V_{GE} = \pm 15 \text{ V}$; $V_{CC} = 600 \text{ V}$; $I_C = 600 \text{ A}$

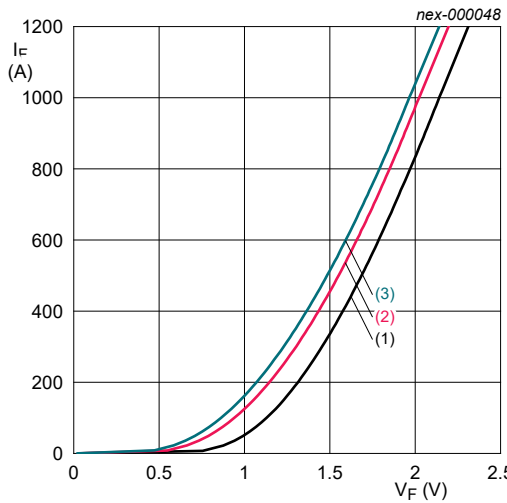
- (1) E_{on} , $T_{vj} = 125 \text{ }^{\circ}\text{C}$
- (2) E_{on} , $T_{vj} = 175 \text{ }^{\circ}\text{C}$
- (3) E_{off} , $T_{vj} = 125 \text{ }^{\circ}\text{C}$
- (4) E_{off} , $T_{vj} = 175 \text{ }^{\circ}\text{C}$

Fig. 12. Typical Switching Energy Losses as a Function of Gate Resistance



i	1	2	3	4
r_i [K/W]	0.000354	0.003298	0.008390	0.067279
τ_i [s]	0.002094	0.008638	0.018028	0.087649

Fig. 13. Transient Thermal Impedance of IGBT as a Function of Single Pulse



- (1) $T_{vj} = 25 \text{ }^{\circ}\text{C}$
- (2) $T_{vj} = 125 \text{ }^{\circ}\text{C}$
- (3) $T_{vj} = 175 \text{ }^{\circ}\text{C}$

Fig. 14. Typical Diode Forward Current as a Function of Forward Voltage, Chip Level

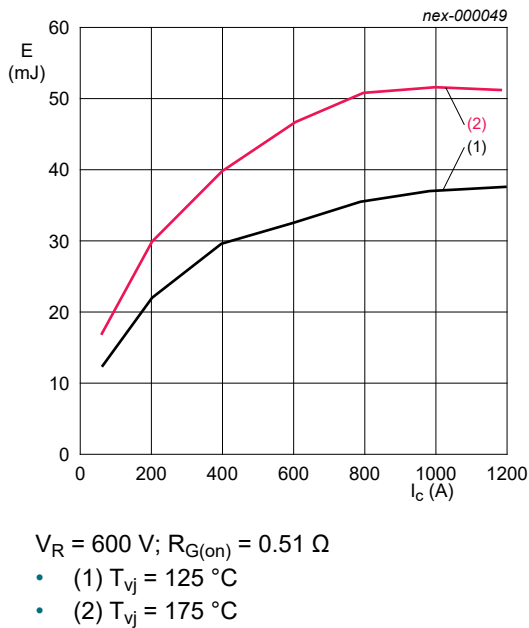


Fig. 15. Typical Reverse Recovery Current as a Function of Forward Current

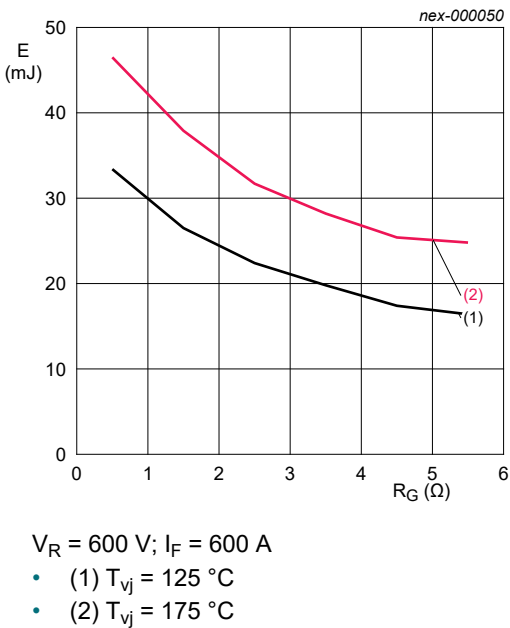
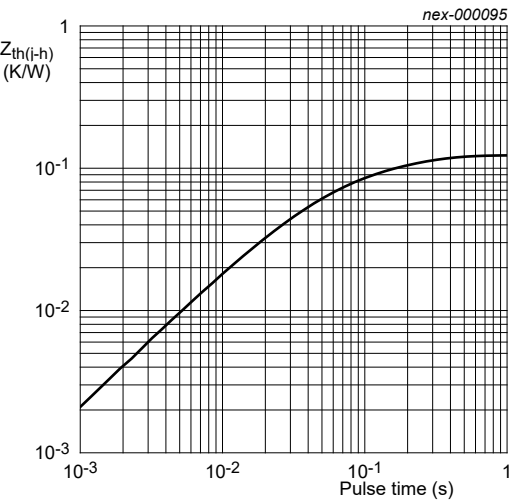


Fig. 16. Typical Reverse Recovery Current as a Function of Gate Resistance



i	1	2	3	4
r_i [K/W]	0.000254	0.016934	0.045328	0.060744
τ_i [s]	0.001857	0.029553	0.043291	0.163099

Fig. 17. Transient Thermal Impedance of Diode as a Function of Single Pulse

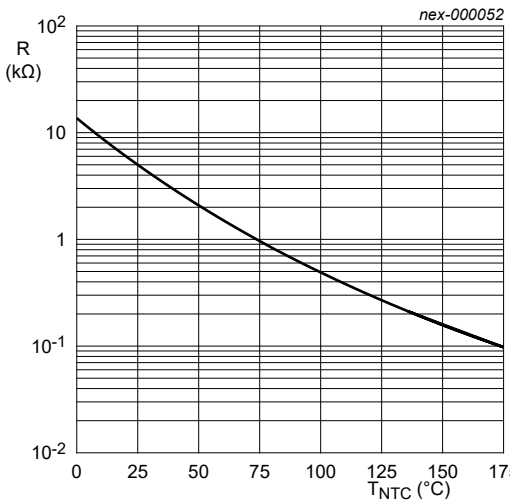


Fig. 18. NTC-thermistor Characteristics

8. Waveform Definition

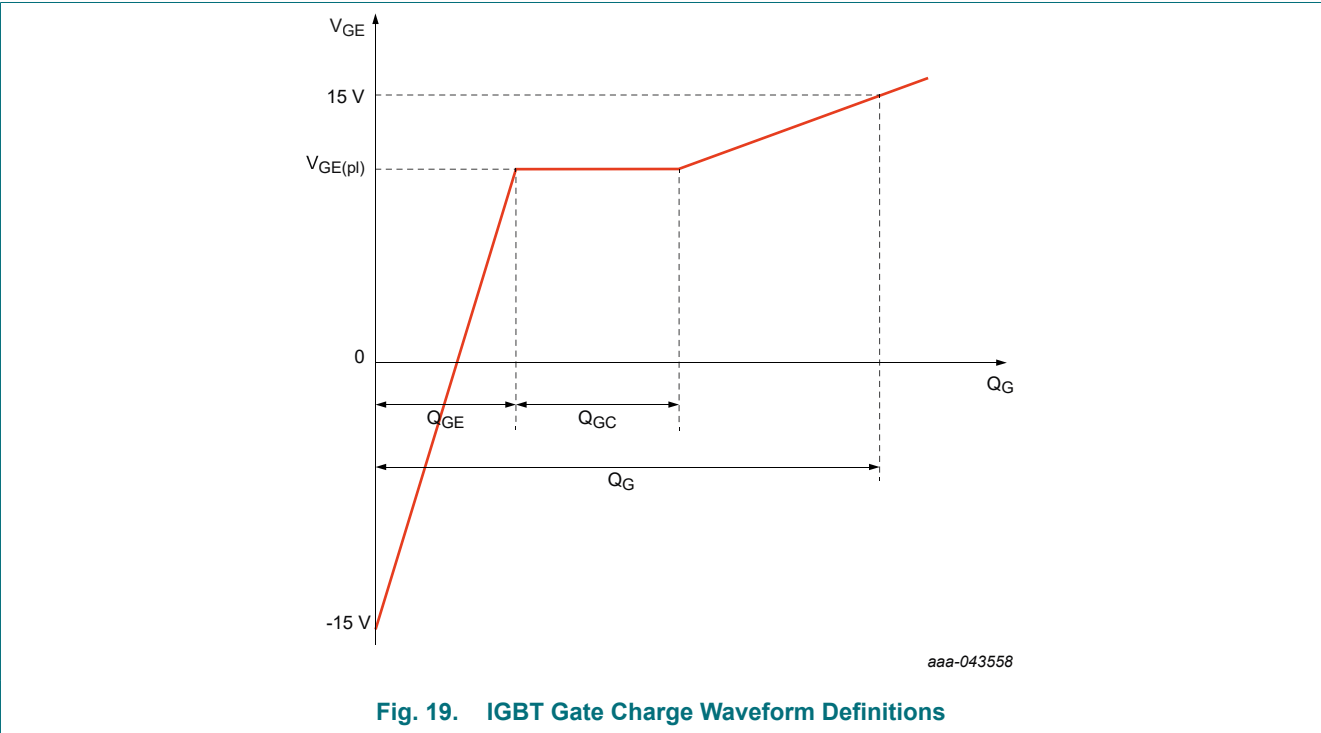


Fig. 19. IGBT Gate Charge Waveform Definitions

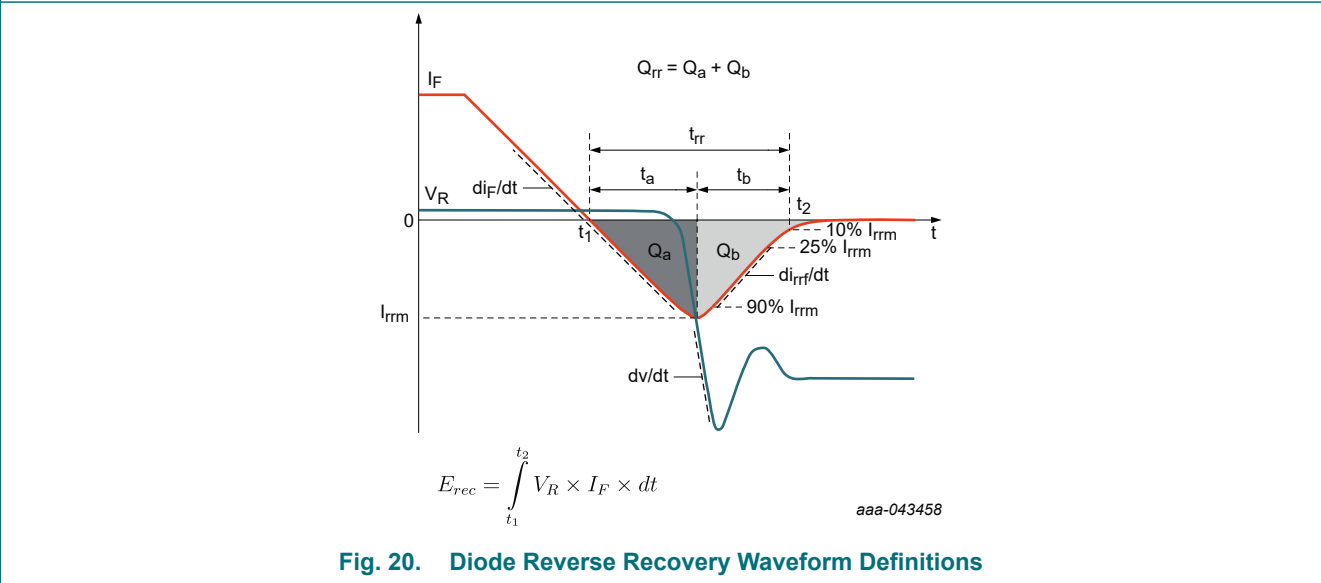
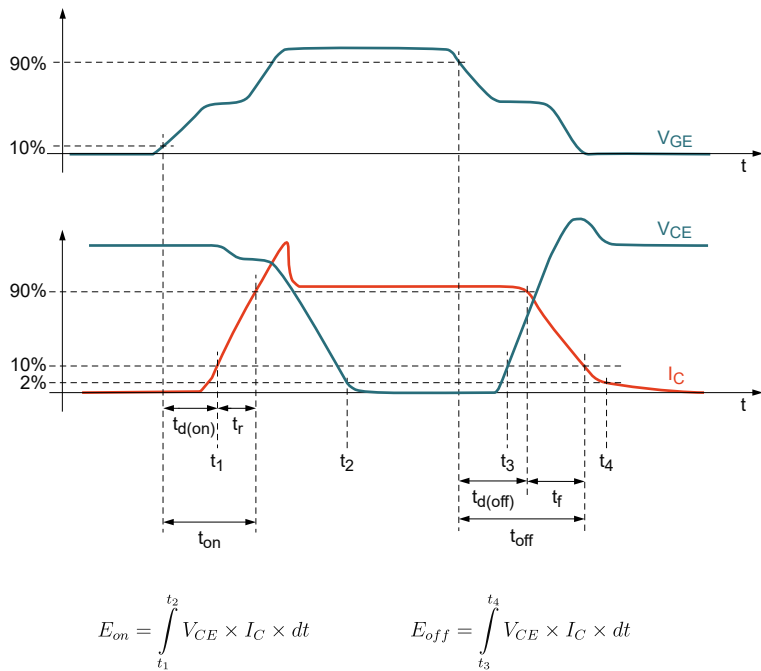


Fig. 20. Diode Reverse Recovery Waveform Definitions



aaa-043459

Fig. 21. IGBT Switching Times and Energy Loss Definitions

9. Circuit Diagram

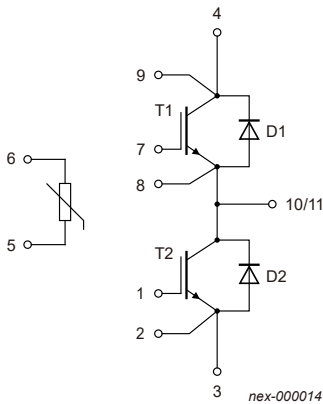


Fig. 22. Circuit Diagram

10. Package Outline

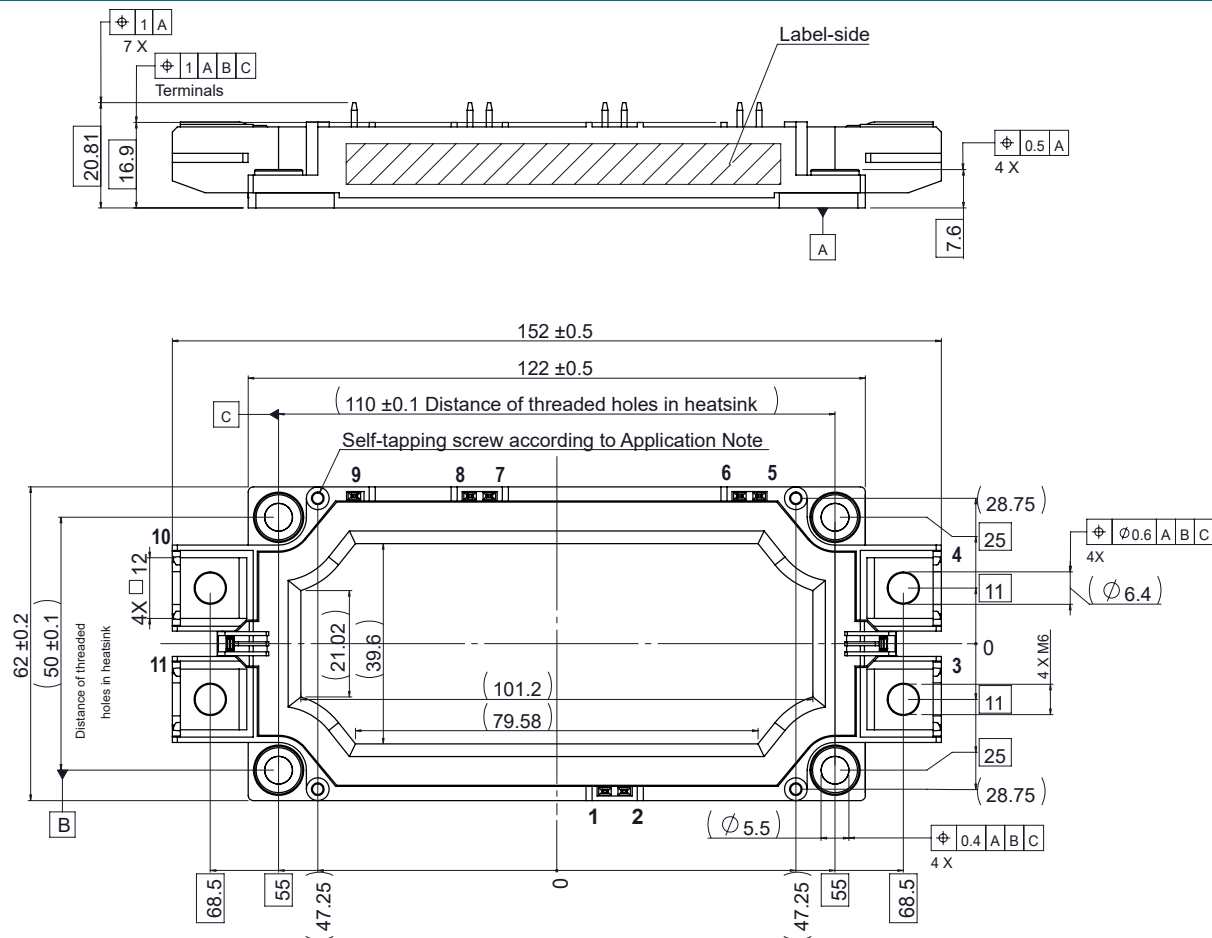
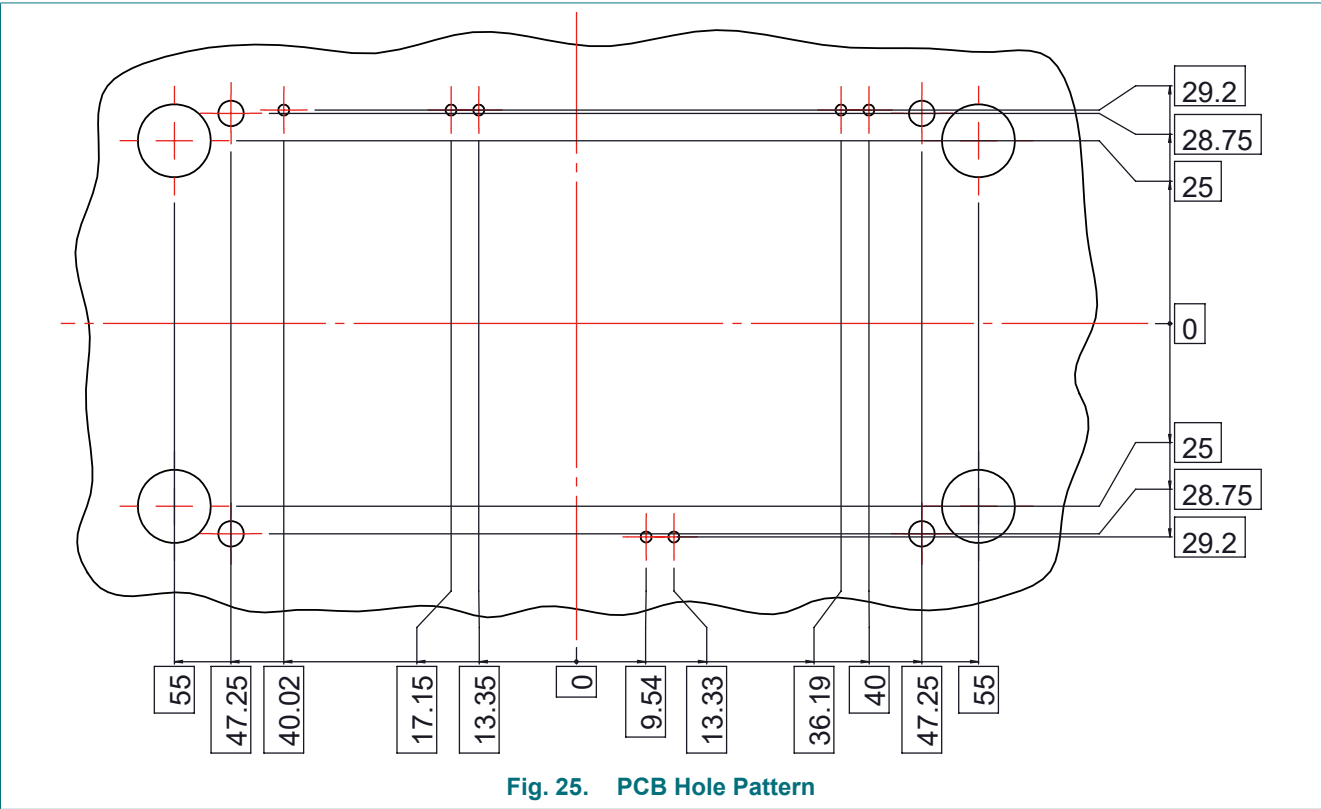
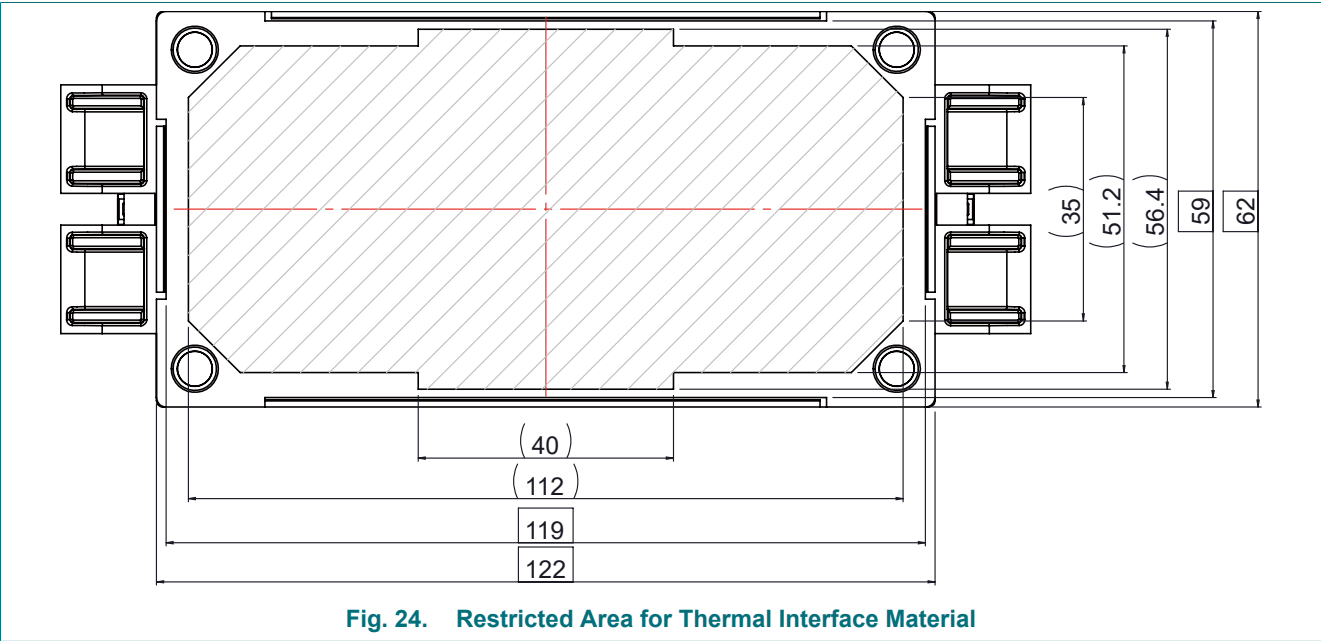


Fig. 23. Package Outline

11. Restricted Area for Thermal Interface Material and PCB Reference



12. Revision History

Table 11. Revision History

Document ID	Release date	Data sheet status	Supersedes
NT600T12D3M7P v. 1	20260625	Product data sheet	-

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nexperia.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1. General Description.....1

2. Features.....1

3. Applications.....1

4. Quick Reference Data.....1

5. Characteristic.....2

5.1. IGBT.....2

5.2. Diode.....3

5.3. NTC Thermistor.....4

5.4. Package.....5

6. Ordering Information.....5

7. Characteristic Diagram.....6

8. Waveform Definition.....10

9. Circuit Diagram.....11

10. Package Outline.....12

11. Restricted Area for Thermal Interface Material
and PCB Reference.....13

12. Revision History.....14

13. Legal information.....15

© Nexperia 2026. All rights reserved

For more information, please visit: <http://www.nexperia.com>
For sales office addresses, please send an email to: salesaddresses@nexperia.com
Date of release: 25 June 2026